

High Voltage Power MOSFET Die

N-Channel Enhancement Mode High Ruggedness Series

The following device types use the IRFC350:

2N6768
 2N6767
 IRF350/IRFP350
 IRF351/IRFP351
 IRF352/IRFP352
 IRF353/IRFP353

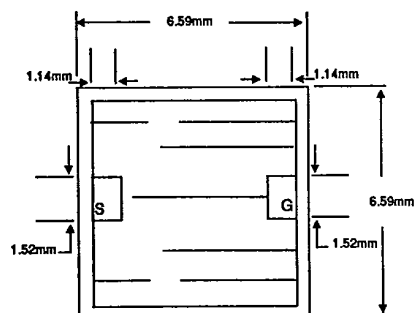
IRFC350

$V_{(BR)DSS}$ 400V
 $R_{DS(on)}$ 0.3 Ω

Die Topography

Notes:

1. Top Metal 3 μ m Aluminum
2. Back Metal Ni/V, with Au
3. Die thickness 420 \pm 10 μ m



FEATURES:

- Fast switching times
- Low $R_{DS(on)}$ HDMOS™ process
- Rugged polysilicon gate cell structure
- Excellent high voltage stability
- Low input capacitance
- Improved high temperature reliability

APPLICATIONS:

- Switching power supplies
- Motor controls
- Audio Amplifiers
- Inverters
- Choppers

ELECTRICAL CHARACTERISTICS: (TA=25 °C unless otherwise specified)

CHARACTERISTIC	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS	
Drain-Source Breakdown Voltage	$V_{GS} = 0$ V, $I_D = 250$ μ A	$V_{(BR)DSS}$	400	—	—	V	
Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250$ μ A	$V_{GS(th)}$	2.0	—	4.0	V	
Gate-Source Leakage Current	$V_{GS} = \pm 20$ VDC	I_{GSS}	—	—	± 100	nA	
Zero Gate Voltage Drain Current	$V_{DS} = V_{(BR)DSS} \times 0.8$, $V_{GS} = 0$ V	I_{DSS}	$T_C = 25^\circ\text{C}$	—	—	250	μ A
			$T_C = 125^\circ\text{C}$	—	—	1000	μ A
Static Drain-Source On-Resistance	$V_{GS} = 10$ V, $I_D = 8.0$ A	$R_{DS(ON)}$	—	—	0.3	Ω	
Ciss Input Capacitance	$V_{GS} = 0$ V, $V_{DS} = 25$ V, $f = 1.0$ MHz	Ciss	—	—	3000	pF	
Coss Output Capacitance	Pulse Test: Pulse width ≤ 300 ms, duty cycle $\leq 2\%$	Coss	—	—	500	pF	
Crss Reverse Transfer Capacitance		Crss	—	—	200	pF	

NOTES:

1. I_D based on $R_{thJC} = 0.83$ °C/W
2. ASSEMBLY RECOMMENDATIONS:
 - a) 10 mil Gate and 15 mil Source wires
 - b) Drain mounted with 92.5/5/2.5% Lead/Indium/Silver solder, or 95/5% Lead/tin solder
3. Devices shipped in ESD protected waffle packs with a maximum of 25 die per waffle pack.
4. Die should be handled and assembled in clean room environment.
5. Die should be stored in inert atmosphere (1 atmosphere N₂)

IXYS Corporation reserves the right to change limits, test conditions, and dimensions without notice.

IXYS Corporation

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